



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

2811  
#7/a  
10/24/2002  
RECEIVED  
TECHNOLOGY CENTER 2800

In re Appln. Of: MAYUZUMI

Serial No.: 10/036,955 ✓

Filed: December 20, 2001

For: SEMICONDUCTOR DEVICE AND METHOD OF ...

Group: 2811

Examiner: IM, JUNGHWA M.

DOCKET: NEC 01FN061

Assistant Commissioner of Patents  
Washington, D.C. 20231

**AMENDMENT B**

Dear Sir:

This Amendment is being filed in response to the Official Action mailed  
August 14, 2002.

Please amend the Application as follows:

**IN THE CLAIMS:**

Please amend claims 1, 2, 3, 7, 8, 9, 11, 12 and 13 to read as follows:

1. (Amended) A semiconductor device comprising:

a semiconductor substrate;

a gate insulation film formed on said semiconductor substrate;

a gate electrode formed on said gate insulation film and having a portion increasing  
upward in the length along a gate length direction, said gate electrode further having a visor  
portion;

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